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# SLD304V

## 1000mW High Power Laser Diode

#### Description

SLD304V are gain-guided, high-power laser diodes fabricated by MOCVD.

MOCVD: Metal Organic Chemical Vapor Deposition

#### Features

- High power Recommended power output Po=900mW
- Small operating current

#### Applications

- Solid state laser excitation
- Medical use

#### Structure

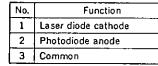
GaAIAs double-hetero laser diode

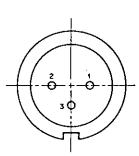
#### Absolute Maximum Ratings (Tc=15°C)

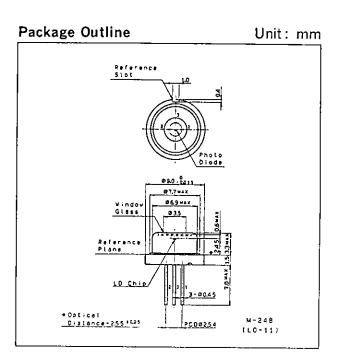
<ul> <li>Radiant power output</li> </ul>	Po		1000	mW
<ul> <li>Reverse voltage</li> </ul>	Vr	LD	2	۷
		PD	15	V
Operating temperature	Topr	-	10 to +30	°C

Storage temperature Tstg −40 to +85 °C

#### Pin Configuration (Bottom View)







 $T_c = 15^{\circ}C$ 

#### **Optical and Electrical Characteristics**

[	tem	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshold curr	ent	ith			500	700	mA
Operating curr	ent	lop	Po=900mW	<b>*</b> 4	1550	2000	mA
Operating volt	age	Vop	Po=900mW		2.1	3.0	V
Wavelength*		λρ	Po=900mW	770		840	nm
Monitor curren	t	lmon	Po=900mW VR=10V		1.5		mA
	e Perpendicular	$\theta \perp$	- Po=900mW	. <u> </u>	28	40	degree
	Parallel	$\theta_{ll}$			13	17	degree
Positional accuracy	Position	ΔΧ, ΔΥ	Po=900mW			±50	μm
	Angle	$\Delta \phi \perp$			······	±3	degree
Slope efficiency	Y	ηD	Po=900mW	0.65	0.85		mW/mA

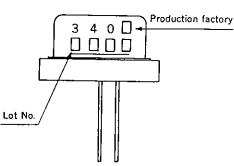
#### \*Wavelength Selection Classification

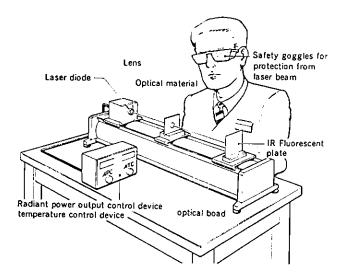
Туре	Wavelength (nm)		
SLD304V-1	785±15		
SLD304V-2	810±10		
SLD304V-3	830±10		
SLD304V-21	798± 3		
-24	807± 3		
-25	810± 3		

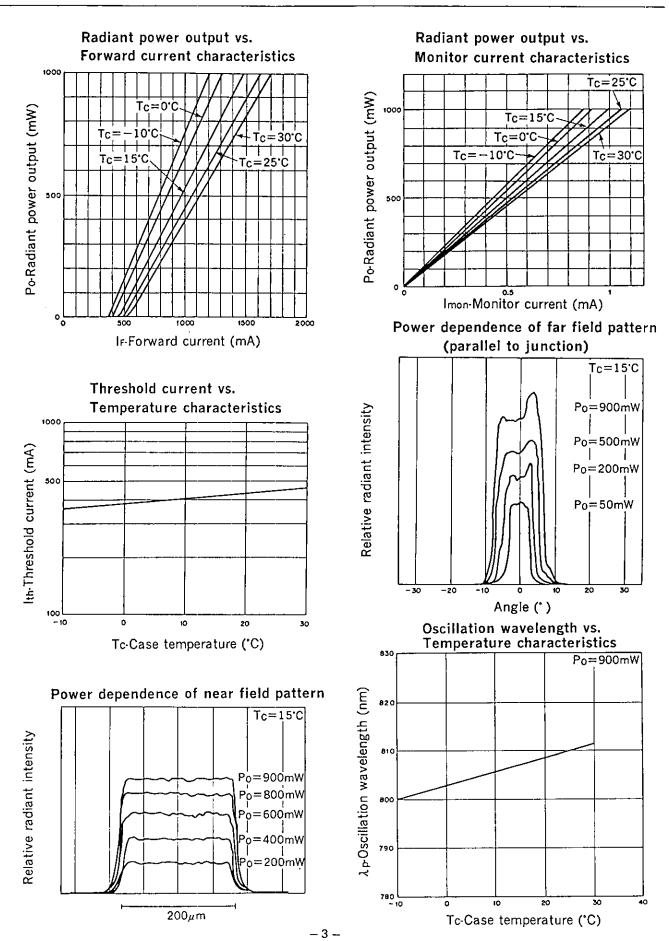
#### Precautions

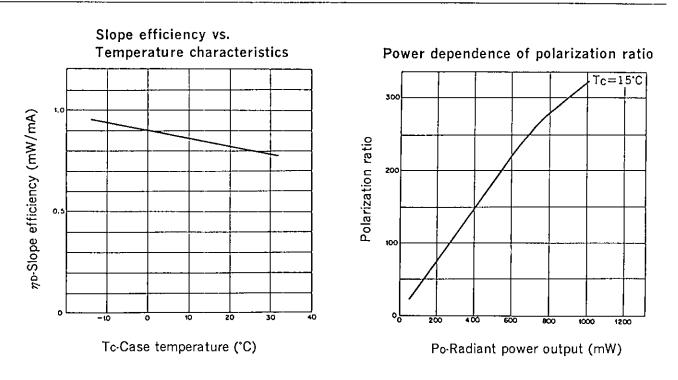
Eye protection against laser beams

The optical output of laser diodes ranges from several milliwatts to one watt. However the optical density of the laser beam at the diode chip reaches 1 megawatt per square centimeter. Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely. Marking



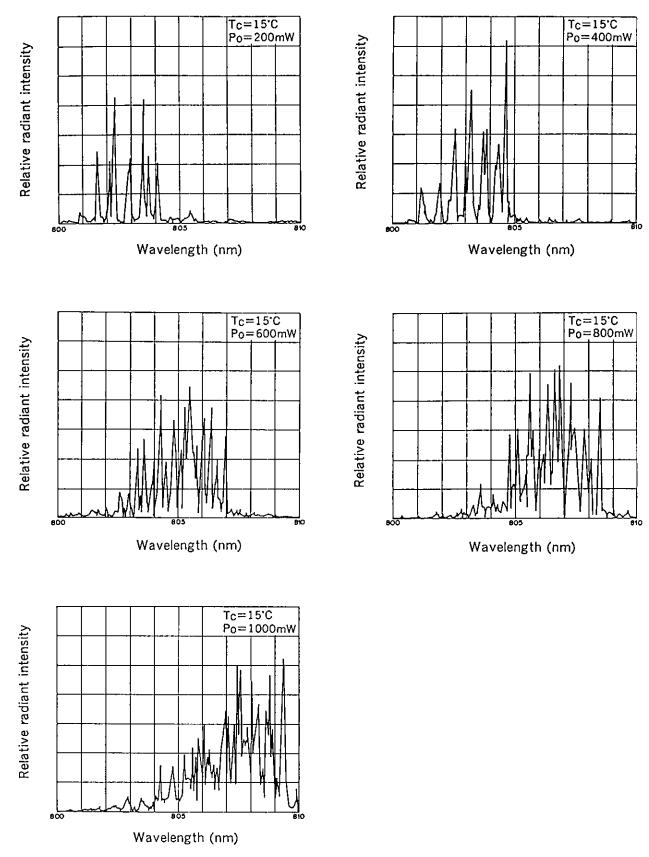






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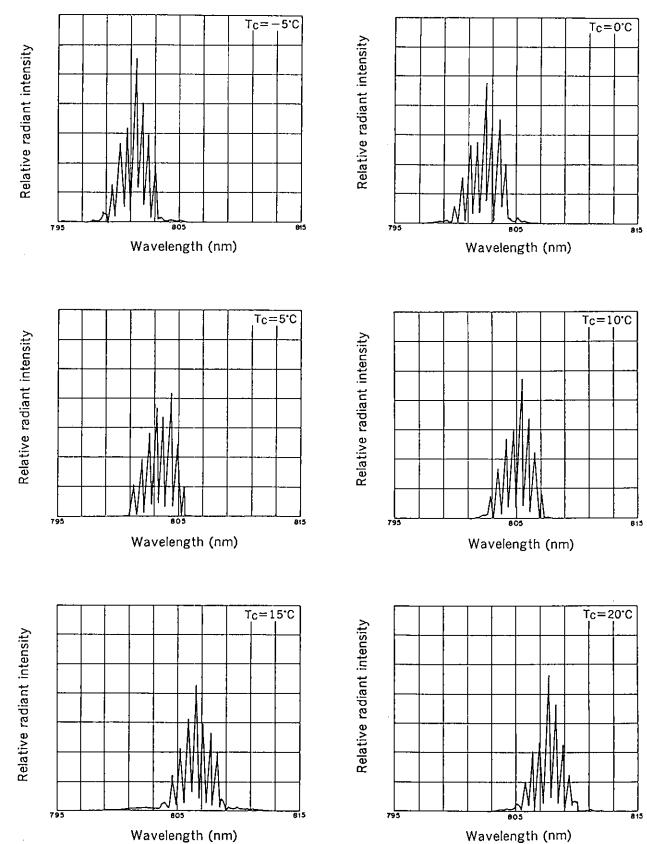
#### Power dependence of wavelength



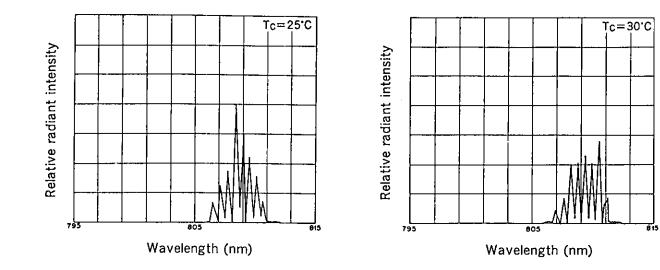
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## Temperature dependence of wavelength (Po=900mW)



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